Vishay Semiconductors

High Performance Schottky Rectifier, 100 A



www.vishay.com

PowerTab[®]

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS			
I _{F(AV)} 100 A			
V _R	45 V		
V _F at I _F	0.71 V		
I _{RM}	320 mA at 125 °C		
T _J max.	150 °C		
E _{AS}	36 mJ		
Package	PowerTab [®]		
Circuit configuration	Single		

FEATURES

- 150 °C max. operating junction temperature
- High frequency operation
- Ultralow forward voltage drop
- Continuous high current operation
- Guard ring for enhanced ruggedness and long term reliability
- Screw mounting only
- AEC-Q101 qualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-100BGQ045HN4 Schottky rectifier has been optimized for ultralow forward voltage drop specifically for low voltage output in high current AC/DC power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MECHANICAL DATA

Case: PowerTab®

Molding compound meets UL 94 V-0 flammability rating

Terminal: nickel plated, screwable

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
	Rectangular waveform	100	A	
IF(AV)	T _C	97	°C	
V _{RRM}		45	V	
I _{FSM}	t _p = 5 μs sine	4400	A	
V _F	100 A _{pk} (typical)	0.65	V	
	TJ	150	°C	
Т _Ј	Range	-55 to +150	۵°	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	100BGQ045	UNITS	
Maximum DC reverse voltage	V _R	45	N.	
Maximum working peak reverse voltage	V _{RWM}	40	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_C = 97 °C, rectangular waveform		100	А
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load	4400	
non-repetitive surge current	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	830	A
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 6 A, L = 2 mH		36	mJ
Repetitive avalanche current	I _{AR}			А	

Revision: 12-Dec-2023

Document Number: 97222

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COMPLIANT HALOGEN



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
	V _{FM} ⁽¹⁾	50 A	T _J = 25 °C	0.54	0.58	
Forward voltage drop		100 A		0.69	0.77	v
Forward voltage drop		50 A	T _J = 150 °C	0.48	0.52	
		100 A		0.65	0.71	
	I _{RM} ⁽¹⁾	T _J = 150 °C, V _R = 45 V		650	1000	
Reverse leakage current		T _J = 25 °C	V _R = Rated V _R	0.3	1	mA
		T _J = 125 °C		180	320	
Maximum junction capacitance	CT	V_R = 5 V_{DC} , (test signal range 100 kHz to 1 MHz) 25 °C		27	00	pF
Typical series inductance	L _S	Measured from tab to mounting plane 3.5		nH		
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/μ		V/µs		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.50 °C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.30	0/11
Approximate weight				5	g
Mounting torque	minimum			1.2 (10)	N · m
	maximum			2.4 (20)	(lbf · in)
Marking device			Case style PowerTab [®]	100BG	Q045H



VS-100BGQ045HN4

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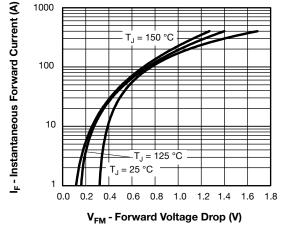


Fig. 1 - Maximum Forward Voltage Drop Characteristics

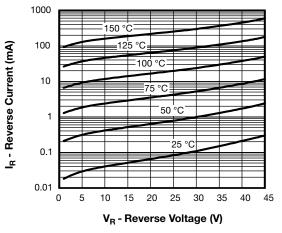


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

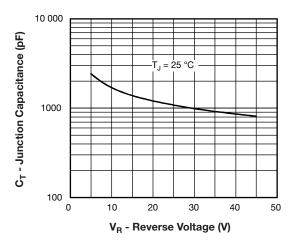
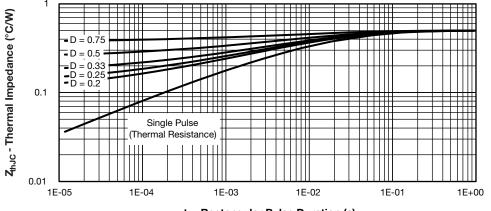


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



 $\mathbf{t_1}$ - Rectangular Pulse Duration (s)

Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

 Revision: 12-Dec-2023
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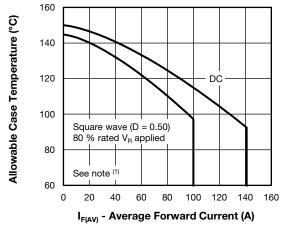
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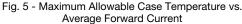
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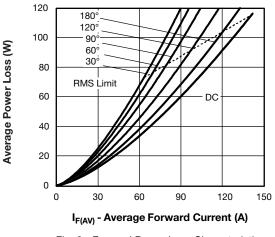


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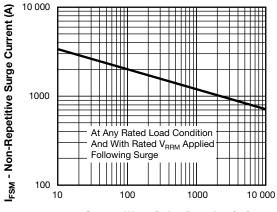
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t - Square Wave Pulse Duration (µs)

Fig. 7 - Maximum Non-Repetitive Surge Current

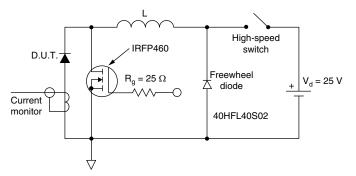


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

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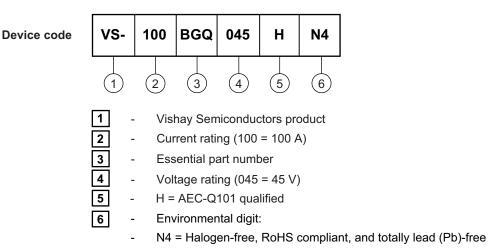
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Antistatic plastic tube

ORDERING INFORMATION TABLE



 ORDERING INFORMATION (Example)

 PREFERRED P/N
 BASE QUANTITY
 PACKAGING DESCRIPTION

LINKS TO R	RELATED DOCUMENTS
Dimensions	www.vishay.com/doc?95240
Part marking information	www.vishay.com/doc?95467
Application note	www.vishay.com/doc?95179

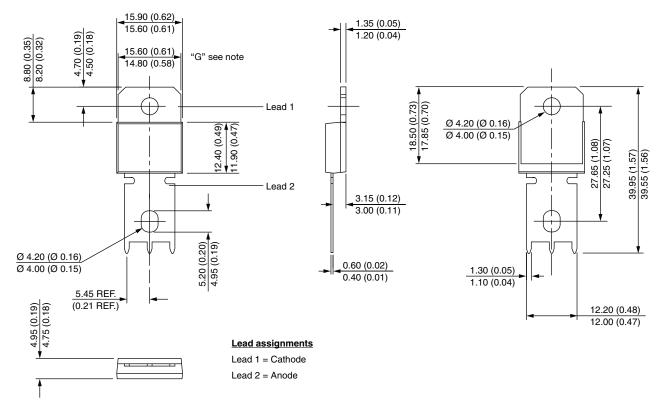
25/tube



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DIMENSIONS in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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Revision: 01-Jan-2025

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